74AUP1G885

Low-power dual function gate

Rev. 13 — 12 August 2024

Product data sheet

1. General description

The 74AUP1G885 is a dual function gate. The output state of the outputs (1Y, 2Y) is determined by the inputs (A, B and C). The output 1Y provides the Boolean function: $1Y = A \times C$. The output 2Y provides the Boolean function: $2Y = \overline{A} \times B + A \times \overline{C}$.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD78 Class II
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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3. Ordering information

Table 1. Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74AUP1G885DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1						
74AUP1G885GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1						
74AUP1G885GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116						
74AUP1G885GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203						

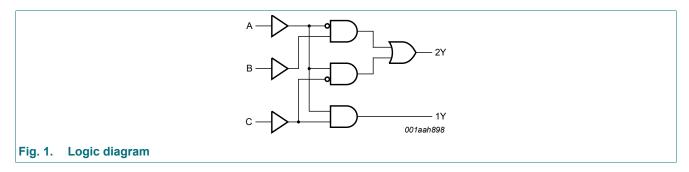
4. Marking

Table 2. Marking codes

Type number	Marking code [1]
74AUP1G885DC	pS8
74AUP1G885GT	pS8
74AUP1G885GN	58
74AUP1G885GS	58

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

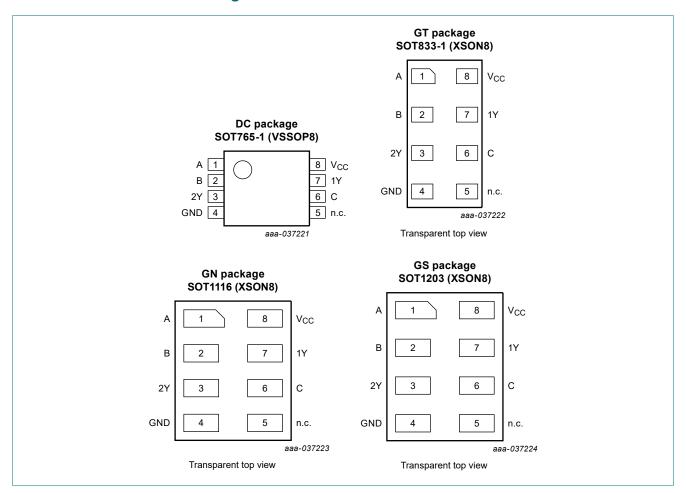
5. Functional diagram



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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
A, B, C	1, 2, 6	data input
GND	4	ground (0 V)
n.c.	5	not connected
1Y, 2Y	7, 3	data output
V _{CC}	8	supply voltage

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7. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input			Output		
A	В	С	1Y	2Y	
L	L	L	L	L	
Н	L	L	L	Н	
L	Н	L	L	Н	
Н	Н	L	L	Н	
L	L	Н	L	L	
Н	L	Н	Н	L	
L	Н	Н	L	Н	
Н	Н	Н	Н	L	

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	$V_{O} < 0 V$	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
I _O	output current	$V_O = 0 \text{ V to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

10010 01	able 6. Operating conditions									
Symbol	Parameter	Conditions	Min	Max	Unit					
V _{CC}	supply voltage		0.8	3.6	V					
VI	input voltage		0	3.6	V					
Vo	output voltage	Active mode	0	V _{CC}	V					
		Power-down mode; V _{CC} = 0 V	0	3.6	V					
T _{amb}	ambient temperature		-40	+125	°C					
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V					

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^[2] For SOT765-1 (VSSOP8) package: P_{tot} derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 $^{\circ}\text{C}.$

For SOT1116 (XSON8) package: Ptot derates linearly with 4.2 mW/K above 90 °C.

For SOT1203 (XSON8) package: Ptot derates linearly with 3.6 mW/K above 81 °C.

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10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C		-			
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage					V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$ to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	40	μΑ
Cı	input capacitance	V_{CC} = 0 V to 3.6 V; V_I = GND or V_{CC}	-	0.6	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.3	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +85 °C				'	
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_I = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μΑ
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μΑ
ΔI _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.6	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH}$ or V_{IL}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
ΔI _{OFF}	additional power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	$V_1 = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	75	μΑ
	·		-			

^[1] One input at V_{CC} - 0.6 V, other inputs at V_{CC} or GND.

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11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 3.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 5 p	F									
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 2</u> [2]								
	delay	V _{CC} = 0.8 V	-	17.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.1	5.2	9.7	0.9	12.8	0.9	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.2	3.7	5.9	1.0	7.8	1.0	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.1	3.0	4.8	0.9	6.2	0.9	6.9	ns
		V _{CC} = 2.3 V to 2.7 V	1.1	2.4	3.6	1.0	4.1	1.0	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.1	2.1	3.1	1.0	3.6	1.0	4.1	ns
		A, B to 2Y; see <u>Fig. 2</u> [2]								
		V _{CC} = 0.8 V	-	21.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.7	6.0	12.7	1.4	12.8	1.4	14.2	ns
		V _{CC} = 1.4 V to 1.6 V	1.7	4.2	7.2	1.4	7.8	1.4	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.4	3.3	5.8	1.2	6.5	1.2	7.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.2	2.6	4.1	1.0	4.7	1.0	5.2	ns
		V _{CC} = 3.0 V to 3.6 V	1.1	2.3	3.5	0.9	3.8	0.9	4.2	ns
C _L = 10	pF									
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 2</u> [2]								
	delay	V _{CC} = 0.8 V	-	20.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.2	6.1	11.4	1.2	14.6	1.2	16.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.4	4.3	7.2	1.2	8.7	1.2	9.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.4	3.6	5.7	1.3	6.8	1.3	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.9	4.2	1.2	4.8	1.2	5.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.7	3.9	1.3	4.1	1.3	4.6	ns
		A, B to 2Y; see <u>Fig. 2</u> [2]								
		V _{CC} = 0.8 V	-	25.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.8	6.9	14.4	1.7	14.6	1.7	16.1	ns
		V _{CC} = 1.4 V to 1.6 V	1.9	4.8	8.5	1.5	9.1	1.5	10.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.2	1.7	8.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	3.1	4.7	1.3	5.4	1.3	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.8	4.3	1.3	4.6	1.3	5.1	ns

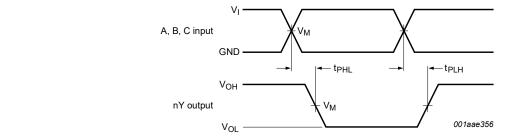
Symbol	Parameter	Parameter Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
C _L = 15	pF		•			•				Ì
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 2</u> [2]								
	delay	V _{CC} = 0.8 V	-	24.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	1.3	6.9	13.0	1.2	16.2	1.2	17.9	ns
		V _{CC} = 1.4 V to 1.6 V	1.7	4.9	8.0	1.4	9.7	1.4	10.8	ns
		V _{CC} = 1.65 V to 1.95 V	1.5	4.1	6.4	1.4	7.6	1.4	8.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.4	5.0	1.6	5.4	1.6	6.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.1	4.4	1.6	4.7	1.6	5.3	ns
		A, B to 2Y; see <u>Fig. 2</u> [2]								
		V _{CC} = 0.8 V	-	28.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.1	7.7	16.0	1.9	16.3	1.9	18.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	5.4	9.4	2.4	10.3	2.4	11.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	4.4	7.4	1.8	8.2	1.8	9.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.6	5.5	1.6	6.0	1.6	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.3	4.8	1.5	5.2	1.5	5.8	ns
C _L = 30	pF					'				
t _{pd}	propagation	A, C to 1Y; see <u>Fig. 2</u> [2]								
	delay	V _{CC} = 0.8 V	-	34.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.4	9.2	17.7	2.3	20.9	2.3	23.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	6.5	10.6	2.5	12.2	2.5	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	5.4	8.5	2.4	9.4	2.4	10.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	4.5	6.4	2.4	7.0	2.4	7.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	4.2	5.7	2.3	6.6	2.3	7.3	ns
		A, B to 2Y; see <u>Fig. 2</u> [2]								
		V _{CC} = 0.8 V	-	38.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	10.0	20.5	2.6	21.5	2.6	23.7	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	6.9	11.9	2.6	13.2	2.6	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	5.7	9.5	2.7	10.5	2.7	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	4.7	6.9	2.5	7.6	2.5	8.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.4	6.1	2.4	7.1	2.4	7.9	ns
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF						•	•	
C _{PD}	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3]								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
	Sapaonanoe	V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.1	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.1	-	-	-	-	-	pF

^[1] All typical values are measured at nominal $V_{\mbox{\scriptsize CC}}.$

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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11.1. Waveforms and test circuit



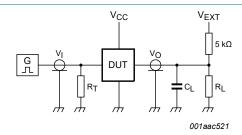
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 2. The data input (A, B, C) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input					
V _{CC}	V _M	V _M	VI	$t_r = t_f$			
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns			



Test data is given in Table 10.

Definitions for test circuit:

R_I = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 3. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 $k\Omega.$

For measuring propagation delays, set-up and hold times and pulse width R_L = 1 $M\Omega$.

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12. Package outline

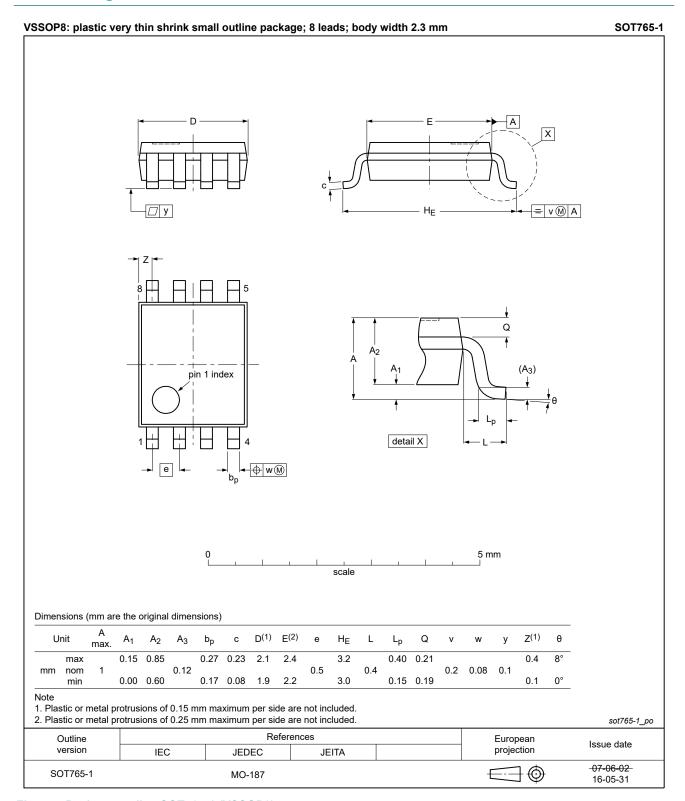


Fig. 4. Package outline SOT765-1 (VSSOP8)

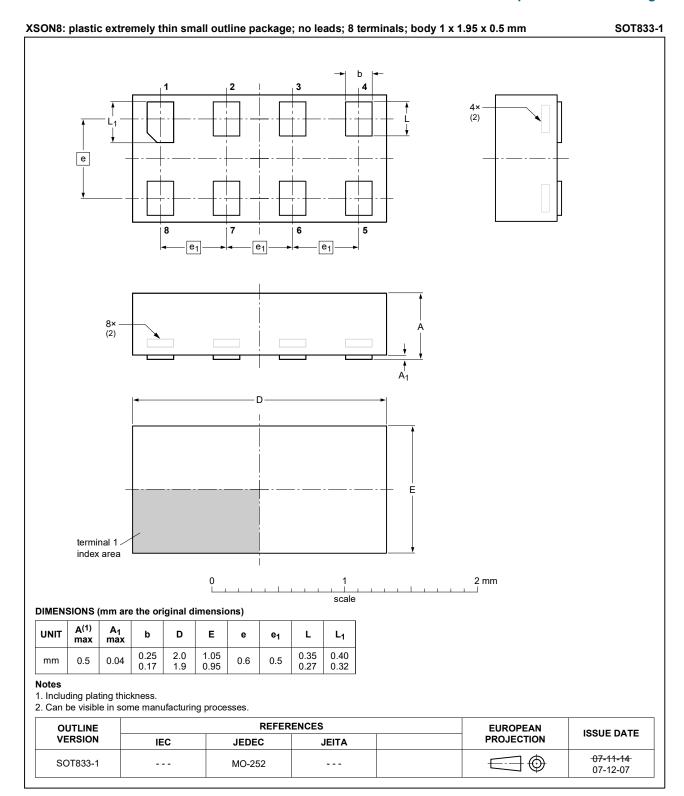


Fig. 5. Package outline SOT833-1 (XSON8)

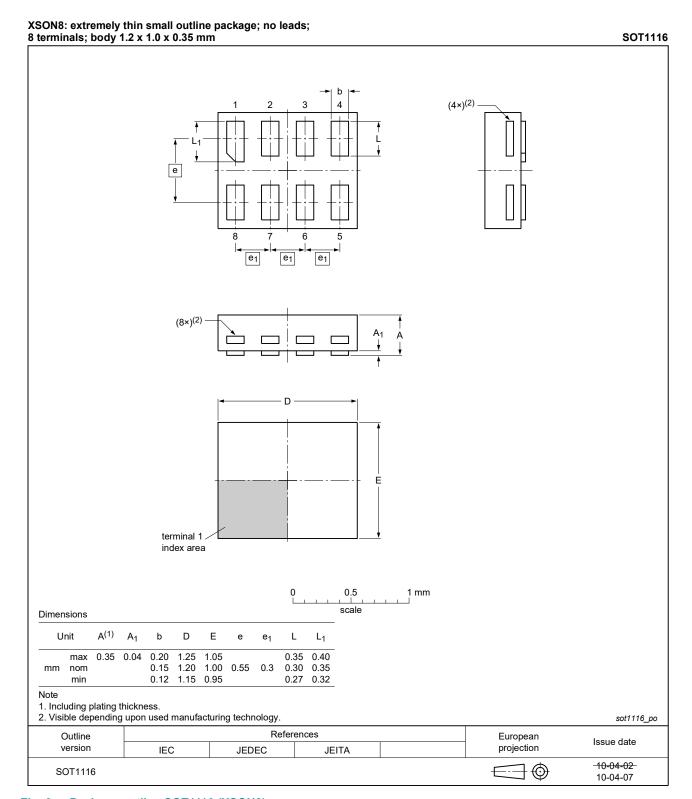


Fig. 6. Package outline SOT1116 (XSON8)

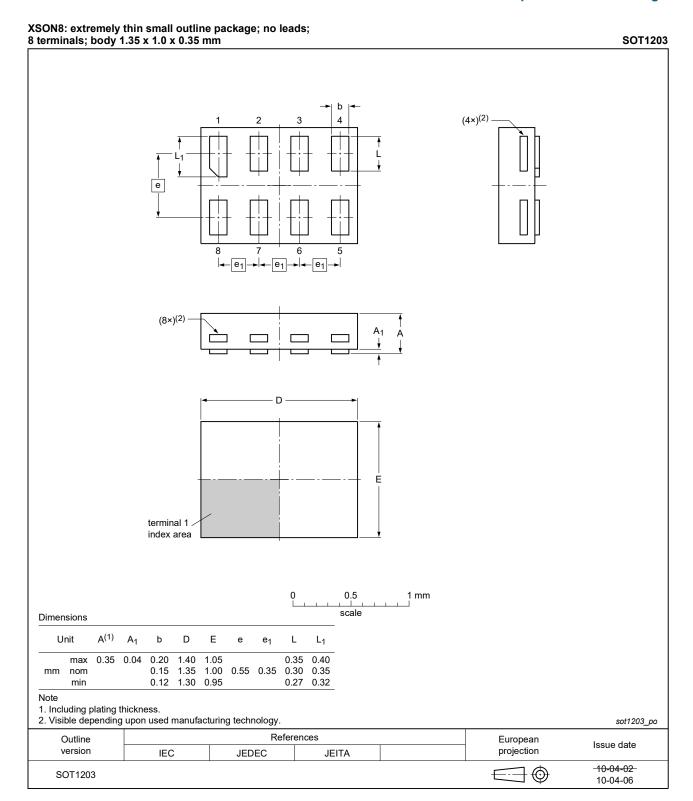


Fig. 7. Package outline SOT1203 (XSON8)

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13. Abbreviations

Table 11. Abbreviations

Acronym	Description
ANSI	American National Standards Institute
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
ESDA	ElectroStatic Discharge Association
НВМ	Human Body Model
JEDEC	Joint Electron Device Engineering Council

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP1G885 v.13	20240812	Product data sheet	-	74AUP1G885 v.12	
Modifications:	Type number	er 74AUP1G885GF (SOT1	1089/XSON8) remo	ved.	
74AUP1G885 v.12	20230728	Product data sheet	-	74AUP1G885 v.11	
Modifications:	Section 2: E	<u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.			
74AUP1G885 v.11	20190722	Product data sheet	-	74AUP1G885 v.10	
Modifications:	* *	 Type number 74AUP1G885GM (SOT902-2) removed. Layout of <u>Table 8</u> Dynamic characteristics updated. 			
74AUP1G885 v.10	20190314	Product data sheet	-	74AUP1G885 v.9	
74AUP1G885 v.9	Type numberPackage out	have been adapted to the er 74AUP1G885GD (SOT9utline drawing SOT765-1 (Vutline drawing SOT902-2 (Vutline drawing SOT	996-2) removed. VSSOP8) updated.	e where appropriate. 74AUP1G885 v.8	
Modifications:		mber 74AUP1G885GD XS	CONOLI has shangs		
			SONOU has change		
74AUP1G885 v.8	20120608	Product data sheet	-	74AUP1G885 v.7	
74AUP1G885 v.7	20111129	Product data sheet	-	74AUP1G885 v.6	
74AUP1G885 v.6	20101021	Product data sheet	-	74AUP1G885 v.5	
74AUP1G885 v.5	20090626	Product data sheet	-	74AUP1G885 v.4	
74AUP1G885 v.4	20090401	Product data sheet	-	74AUP1G885 v.3	
74AUP1G885 v.3	20080328	Product data sheet	-	74AUP1G885 v.2	
74AUP1G885 v.2	20070710	Product data sheet	-	74AUP1G885 v.1	
74AUP1G885 v.1	20061201	Product data sheet	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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